



XV Krajowa Szkoła Nadprzewodnictwa
”Stulecie Nadprzewodnictwa”
Kazimierz Dolny, 9-13 października 2011 r.

**Structure and transport properties of nitrated VN-SiO₂
sol-gel derived films**

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This work presents results of transport properties studies of x VN-(100- x)SiO₂ (where $x = 90, 80, 70, 60$ mol%) films. The films were prepared by thermal nitridation of sol-gel derived V₂O₃-SiO₂ (in proper molar ratio) coatings. The coatings obtained by sol-gel method are especially suitable for the ammonolysis because of their porosity. The microporous structure allows both a significant incorporation of nitrogen and its distribution through the film. The nitridation process of V₂O₃ -SiO₂ coatings leads to the formation of disordered structures, with VN metallic grains dispersed in the matrix of insulating SiO₂. The critical temperatures of the superconducting transition of the samples, T_{conset} , are about 7.5 K.